ENT COOPERATION TREATY

From the INTERNATIONAL SEARCHING AUTHORITY

SEMICONDUCTOR ENERGY LABORATORY CO., LTD.

398, Hase, Atsugi-shi, Kanagawa 2430036 Japan

WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY (PCT Rule 43bis.1)

Date of mailing (day/month/year)

04.10.2005

Applicant's or agent's file reference 00000PCT7956

FOR FURTHER ACTION

See paragraph 2 below

International application No. PCT/JP2005/011397 International filing date (day/month/year)

Priority date (day/month/year)

15.06.2005

18.06.2004

International Patent Classification (IPC) or both national classification and IPC Int.Cl. H01L21/268, 21/20, 21/336, 29/786

Applicant

SEMICONDUCTOR ENERGY LABORATORY CO., LTD.

 This opinion contains indications relating to the following it 	tems:
--	-------

V Box No. I Basis of the opinion

Box No. II **Priority**

Box No. III Non-establishment of opinion with regard to novelty, inventive step and industrial applicability

Box No. IV Lack of unity of invention

Box No. V Reasoned statement under Rule 43bis.1(a)(i) with regard to novelty, inventive step or industrial applicability;

citations and explanations supporting such statement

Box No. VI Certain documents cited

Box No. VII Certain defects in the international application

Box No. VIII Certain observations on the international application

2. FURTHER ACTION

If a demand for international preliminary examination is made, this opinion will be considered to be a written opinion of the International Preliminary Examining Authority ("IPEA") except that this does not apply where the applicant chooses an Authority other than this one to be the IPEA and the chosen IPEA has notified the International Bureau under Rule 66.1 bis(b) that written opinions of this International Searching Authority will not be so considered.

If this opinion is, as provided above, considered to be a written opinion of the IPEA, the applicant is invited to submit to the IPEA a written reply together, where appropriate, with amendments, before the expiration of 3 months from the date of mailing of Form PCT/ISA/220 or before the expiration of 22 months from the priority date, whichever expires later.

For further options, see Form PCT/ISA/220.

3. For further details, see notes to Form PCT/ISA/220.

Date of completion of this opinion 15.09.200	5			
Name and mailing address of the ISA/JP	Authorized officer	-	4L	9835
Japan Patent Office	SHUJI HAGIWARA		L1	
3-4-3, Kasumigaseki, Chiyoda-ku, Tokyo 100-8915, Japan	Telephone No. +81-3-3581-1101	Ext.	3498	

WRIEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

Int. ional application No.

PCT/JP2005/011397

Bo	k No. I	Basis of the opinion
1.		gard to the language, this opinion has been established on the basis of the international application in the language in was filed, unless otherwise indicated under this item.
		his opinion has been established on the basis of a translation from the original language into the following language, which is the language of a translation furnished for the purposes of international search (under tules 12.3 and 23.1(b)).
	•	·
2.	With reg	gard to any nucleotide and/or amino acid sequence disclosed in the international application and necessary to the invention, this opinion has been established on the basis of:
	a type o	of material
•		a sequence listing
	_	table(s) related to the sequence listing
	b. forma	t of material
	Г	in written format
	Γ	in computer readable form
		·
	c. time o	f filing/furnishing
		contained in the international application as filed.
	Γ	filed together with the international application in computer readable form.
		furnished subsequently to this Authority for the purposes of search.
3.	fil	addition, in the case that more than one version or copy of a sequence listing and/or table relating thereto has been ed or furnished, the required statements that the information in the subsequent or additional copies is identical to that the application as filed or does not go beyond the application as filed, as appropriate, were furnished.
4	A 4 4:4:	
4.	Addition	al comments:
		(4)
		_
		·

WRIT N OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

Inter; nal application No.
PCT/JP2005/011397

Box No. IV	Lack of unity of invention
In response	e to the invitation (Form PCT/ISA/206) to pay additional fees the applicant has:
•	
Г	paid additional fees
Г	paid additional fees under protest
F :	not paid additional fees
	authority found that the requirement of unity of invention is not complied with and chose not to invite the applicant to ditional fees.
3. This Autho	rity considers that the requirement of unity of invention in accordance with Rule 13.1, 13.2 and 13.3 is
Com	uplied with
_	complied with for the following reasons:
claims beam, a scannin Howev apparen 2000-34 documen over th Conse feature there is	same or corresponding matters (A) between the inventions of Nos. 1-48 are "scanning the irradiation surface with a laser nd wherein beam intensity can be varied in accordance with a lag direction." ver, after taking the prior art into consideration, it became at that the matters (A) were mentioned in a document JP 0403 A (SEIKO EPSON KABUSHIKI KAISHA), 2000.12.08, the whole t, figs. 1-7. Therefore, the matters (A) makes no contribution the prior art. Equently, there is no same or corresponding "special technical s" which is the expression in the PCT Rule 13.2. Therefore, s no technical relationship between the inventions of claims -5], [6-12], [13-21], [22-30], [31-39] and [40-48].
claims Nescanning beam in a second the fir However apparent 2000-34 document over the Consefeatures there is	same or corresponding matters(B) between the inventions of Nos. 1-5 are "delivering a laser beam to semiconductor layer; g the semiconductor layer to a first direction with the laser a first intensity; and scanning the semiconductor layer to direction with the laser beam in a second intensity, wherein st intensity is larger than the second intensity." For, after taking the prior art into consideration, it became that the matters(B) were mentioned in a document JP 0403 A (SEIKO EPSON KABUSHIKI KAISHA), 2000.12.08, the whole the time of the matters (B) makes no contribution to prior art. Equently, there is no same or corresponding "special technical sequently, there is no same or corresponding "special technical sequently relationship between the inventions of claims and technical relationship between the inventions of claims and [5].
┌ all p	tly, this opinion has been established in respect of the following parts of the international application: parts.

WRI PN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

Claims

Claims

Intentional application No.

PCT/JP2005/011397

YES

NO

Box No. V Reasoned statement under Rule 43bis.1(a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

1. Statement

Novelty (N)

Claims

Claims

Claims

Claims

Claims

TES

NO

Inventive step (IS)

Claims

Claims

Claims

Claims

Claims

NO

NO

2. Citations and explanations

Industrial applicability (IA)

D1: JP 2000-340503 A (SEIKO EPSON KABUSHIKI KAISHA) 2000.12.08, the whole document, figs. 1-7

D2:EP 1304186 A2 (SEMICONDUCTOR ENERGY LABORATORY CO., LTD.) 2003.04.23, the whole document, figs. 1-28

D3:JP 2004-172424 A (KABUSHIKI KAISHA NIHON SEIKOUSHO) 2004.06.17, the whole document, figs. 1-19

Novelty: Concerning claims 1

The subject matters of claim 1 do not appear to involve a novelty with respect to the cited document D1.

The cited document D1 (paragraphs [0006]-[0009]) discloses a laser irradiation method comprising: delivering a laser beam to a semiconductor layer; scanning the semiconductor layer to a first direction with the laser beam in a first intensity; and scanning the semiconductor layer to a second direction with the laser beam in a second intensity, wherein the first intensity is larger than the second intensity.

Inventive Step: Concerning claims 2

The subject matters of claim 2 do not appear to involve an inventive step with respect to the cited document D1, D2 and D3.

The cited document D2 (fig. 1) and D3 (fig. 1) disclose a laser irradiation method wherein the laser beam is delivered obliquely to a semiconductor layer.

On the basis of these disclosures of D2 and D3, a person skilled in the art could easily realize a laser irradiation method comprising: delivering a laser beam to a semiconductor layer; scanning the semiconductor layer to a first direction with the laser beam in a first intensity; scanning the semiconductor layer to a second direction with the laser beam in a second intensity, wherein the first intensity is larger than the second intensity and the laser beam is delivered obliquely to a semiconductor layer.

WRI N OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

Integration No.

PCT/JP2005/011397

Supplemental Box

In case the space in any of the preceding boxes is not sufficient.

Continuation of: IV.3

The same or corresponding matters(C) between the inventions of claims Nos. 6-12 are "emitting a first laser beam; changing the first laser beam into a second laser beam through means for varying beam intensity which can vary beam intensity in accordance with a scanning direction; changing the second laser beam into a third laser beam; delivering the third laser beam to an irradiation surface; and scanning the irradiation surface with the third laser beam."

However, after taking the prior art into consideration, it became apparent that the matters(C) were mentioned in a document JP 2000-340403 A (SEIKO EPSON KABUSHIKI KAISHA), 2000.12.08, the whole document, figs. 1-7. Therefore, the matters(C) makes no contribution over the prior art.

Consequently, there is no same or corresponding "special technical features" which is the expression in the PCT Rule 13.2. Therefore, there is no technical relationship between the inventions of claims Nos. [6, 7], [8], [9], [10], [11] and [12].

The same or corresponding matters(D) between the inventions of claims Nos. 13-21 are "A laser irradiation apparatus comprising: a laser oscillator; means for varying beam intensity; and a convex lens; wherein a laser beam is incident into an irradiation surface, wherein the irradiation surface is scanned with the laser beam, and wherein beam intensity is varied in every scanning direction by the means for varying beam intensity."

However, after taking the prior art into consideration, it became apparent that the matters(D) were mentioned in a document JP 2000-340403 A (SEIKO EPSON KABUSHIKI KAISHA), 2000.12.08, the whole document, figs. 1-7 and EP 1304186 A2 (SEMICONDUCTOR ENERGY LABORATORY CO., LTD.), 2003.04.23, the whole document, figs. 1-28. Therefore, the matters(D) makes no contribution over the prior art.

Consequently, there is no same or corresponding "special technical features" which is the expression in the PCT Rule 13.2. Therefore, there is no technical relationship between the inventions of claims Nos. [13, 14], [15, 16], [17], [18], [19], [20] and [21].

WR: EN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

Int: Prional application No.
PCT/JP2005/011397

Supplemental Box

In case the space in any of the preceding boxes is not sufficient.

Continuation of: IV.3

The same or corresponding matters(E) between the inventions of claims Nos. 22-30 are "A laser irradiation apparatus comprising: a laser oscillator; means for varying beam intensity; and a diffractive optical element; wherein a laser beam is incident into an irradiation surface, wherein the irradiation surface is scanned with the laser beam, and wherein beam intensity is varied in every scanning direction by the means for varying beam intensity."

However, after taking the prior art into consideration, it became apparent that the matters(E) were mentioned in a document JP 2000-340403 A (SEIKO EPSON KABUSHIKI KAISHA), 2000.12.08, the whole document, figs. 1-7 and EP 1304186 A2 (SEMICONDUCTOR ENERGY LABORATORY CO., LTD.), 2003.04.23, the whole document, figs. 1-28. Therefore, the matters(E) makes no contribution over the prior art.

Consequently, there is no same or corresponding "special technical features" which is the expression in the PCT Rule 13.2. Therefore, there is no technical relationship between the inventions of claims Nos. [22, 23], [24, 25], [26], [27], [28], [29] and [30].

The same or corresponding matters(F) between the inventions of claims Nos. 31-39 are "A laser irradiation apparatus comprising: a laser oscillator; means for varying beam intensity; and a convex lens; wherein a laser beam is incident obliquely into an irradiation surface, wherein the irradiation surface is scanned with the laser beam, and wherein beam intensity is varied in every scanning direction by the means for varying beam intensity."

However, after taking the prior art into consideration, it became apparent that the matters(F) were mentioned in a document JP 2000-340403 A (SEIKO EPSON KABUSHIKI KAISHA), 2000.12.08, the whole document, figs. 1-7 and EP 1304186 A2 (SEMICONDUCTOR ENERGY LABORATORY CO., LTD.), 2003.04.23, the whole document, figs. 1-28. Therefore, the matters(F) makes no contribution over the prior art.

Consequently, there is no same or corresponding "special technical features" which is the expression in the PCT Rule 13.2. Therefore, there is no technical relationship between the inventions of claims Nos. [31, 32], [33, 34], [35], [36], [37], [38] and [39].

WRI N OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

International application No.

FCT/JP2005/011397

Supplemental Box

In case the space in any of the preceding boxes is not sufficient.

Continuation of: IV.3

The same or corresponding matters (G) between the inventions of claims Nos. 40-48 are "A laser irradiation apparatus comprising: a laser oscillator; means for varying beam intensity; and a diffractive optical element; wherein a laser beam is incident obliquely, into an irradiation surface, wherein the irradiation surface is scanned with the laser beam, and wherein beam intensity is varied in every scanning direction by the means for varying beam intensity."

However, after taking the prior art into consideration, it became apparent that the matters(G) were mentioned in a document JP 2000-340403 A (SEIKO EPSON KABUSHIKI KAISHA), 2000.12.08, the whole document, figs. 1-7 and EP 1304186 A2 (SEMICONDUCTOR ENERGY LABORATORY CO., LTD.), 2003.04.23, the whole document, figs. 1-28. Therefore, the matters(G) makes no contribution over the prior art.

Consequently, there is no same or corresponding "special technical features" which is the expression in the PCT Rule 13.2. Therefore, there is no technical relationship between the inventions of claims Nos. [40, 41], [42, 43], [44], [45], [46], [47] and [48].

Consequently, there is no same or corresponding "special technical features" which is the expression in the PCT Rule 13.2. Therefore, there is no technical relationship between the inventions of claims Nos. [1, 2], [3], [4], [5], [6, 7], [8], [9], [10], [11], [12], [13, 14], [15, 16], [17], [18], [19], [20], [21], [22, 23], [24, 25], [26], [27], [28], [29], [30], [31, 32], [33, 34], [35], [36], [37], [38], [39], [40, 41], [42, 43], [44], [45], [46], [47] and [48].